Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Overall Length:
Between 0.37 inches and 0.41 inches
Internal Configuration:
Field effect
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 gate to source voltage
Current Rating Per Characteristic:
9.4 amperes source current
Power Rating Per Characteristic:
48.0 watts total device dissipation
Product Name:
Hexfet, power mosfet, surface mount
Terminal Type And Quantity:
3 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0